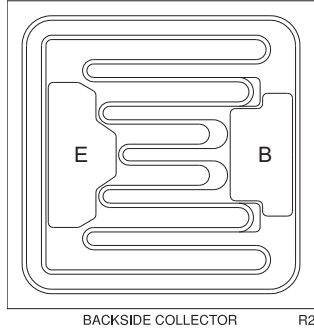


CP305V-2N718A

NPN - Small Signal Transistor Die

50 Volt

The CP305V-2N718A is a silicon NPN small signal transistor designed for general purpose amplifier and switching applications.



MECHANICAL SPECIFICATIONS:

Die Size	31.1 x 31.1 MILS
Die Thickness	7.1 MILS
Base Bonding Pad Size	5.9 x 11.8 MILS
Emitter Bonding Pad Size	6.5 x 13.8 MILS
Top Side Metalization	Al – 13,000Å
Back Side Metalization	Au/As-Au – 9,000Å
Scribe Alley Width	1.96 MILS
Wafer Diameter	5 INCHES
Gross Die Per Wafer	17,534

MAXIMUM RATINGS: ($T_A=25^{\circ}\text{C}$)

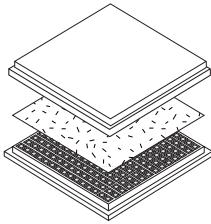
	SYMBOL		UNITS
Collector-Base Voltage	V_{CBO}	75	V
Collector-Emitter Voltage	V_{CER}	50	V
Emitter-Base Voltage	V_{EBO}	7.0	V
Operating and Storage Junction Temperature	T_J, T_{stg}	-65 to +150	$^{\circ}\text{C}$

ELECTRICAL CHARACTERISTICS: ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
I_{CBO}	$V_{CB}=60\text{V}$		10	nA
I_{EBO}	$V_{EB}=5.0\text{V}$		10	nA
BV_{CBO}	$I_C=100\mu\text{A}$	75		V
BV_{CER}	$I_C=100\text{mA}, R_{BE}=10\Omega$	50		V
BV_{EBO}	$I_E=100\mu\text{A}$	7.0		V
$V_{CE(SAT)}$	$I_C=150\text{mA}, I_B=15\text{mA}$		1.5	V
$V_{BE(SAT)}$	$I_C=150\text{mA}, I_B=15\text{mA}$		1.3	V
h_{FE}	$V_{CE}=10\text{V}, I_C=0.1\text{mA}$	20		
h_{FE}	$V_{CE}=10\text{V}, I_C=10\text{mA}$	35		
h_{FE}	$V_{CE}=10\text{V}, I_C=150\text{mA}$	40	120	
h_{FE}	$V_{CE}=10\text{V}, I_C=500\text{mA}$	20		
f_T	$V_{CE}=10\text{V}, I_C=50\text{mA}, f=20\text{MHz}$	60		MHz
C_{ob}	$V_{CB}=10\text{V}, I_E=0, f=100\text{kHz}$		25	pF
C_{ib}	$V_{EB}=0.5\text{V}, I_C=0, f=100\text{kHz}$		80	pF
h_{ib}	$V_{CB}=5.0\text{V}, I_C=1.0\text{mA}, f=1.0\text{kHz}$	24	34	Ω
h_{ib}	$V_{CB}=10\text{V}, I_C=5.0\text{mA}, f=1.0\text{kHz}$	4.0	8.0	Ω
h_{rb}	$V_{CB}=5.0\text{V}, I_C=1.0\text{mA}, f=1.0\text{kHz}$		3.0	$\times 10^{-4}$
h_{rb}	$V_{CB}=10\text{V}, I_C=5.0\text{mA}, f=1.0\text{kHz}$		3.0	$\times 10^{-4}$
h_{fe}	$V_{CE}=5.0\text{V}, I_C=1.0\text{mA}, f=1.0\text{kHz}$	30	100	
h_{fe}	$V_{CE}=10\text{V}, I_C=5.0\text{mA}, f=1.0\text{kHz}$	35	150	
h_{ob}	$V_{CB}=5.0\text{V}, I_C=1.0\text{mA}, f=1.0\text{kHz}$	0.05	0.5	μS
h_{ob}	$V_{CB}=10\text{V}, I_C=5.0\text{mA}, f=1.0\text{kHz}$	0.05	0.5	μS
NF	$V_{CE}=10\text{V}, I_C=300\mu\text{A}, f=1.0\text{kHz}$		12	dB

R0 (29-April 2019)

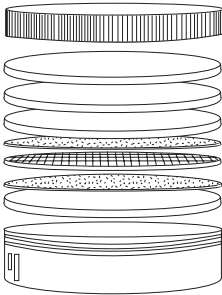
BARE DIE PACKING OPTIONS



BARE DIE IN TRAY (WAFFLE) PACK

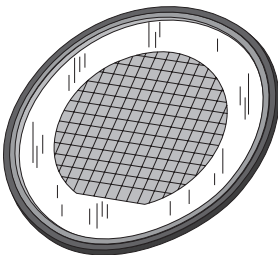
CT: Singulated die in tray (waffle) pack.
(example: CP211-PART NUMBER-CT)

CM: Singulated die in tray (waffle) pack 100% visually inspected as per MIL-STD-750, (method 2072 transistors, method 2073 diodes).
(example: CP211-PART NUMBER-CM)



UNSAWN WAFER

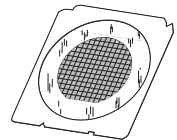
WN: Full wafer, unsawn, 100% tested with reject die inked.
(example: CP211-PART NUMBER-WN)



SAWN WAFER ON PLASTIC RING

WR: Full wafer, sawn and mounted on plastic ring,
100% tested with reject die inked.
(example: CP211-PART NUMBER-WR)

Please note: Sawn Wafer on Metal Frame (WS) is possible as a special order. Please contact your Central Sales Representative at 631-435-1110.



Visit the Central website for a complete listing of specifications:
www.centrasemi.com/bdspecs

OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options
- Custom bar coding for shipments
- Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- Environmental regulation compliance
- Customer specific screening
- Up-screening capabilities
- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- Application and design sample kits
- Custom product and package development

REQUESTING PRODUCT PLATING

1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
2. If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

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